

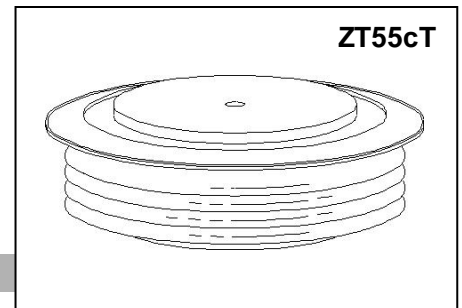


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**GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER**

**Features:**

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 3500 volts
- . Ceramic Housing Hermetic Package
- . Pressure Assembled Device



**ELECTRICAL CHARACTERISTICS AND RATINGS**

**Reverse Blocking**

Device Type	V <sub>RRM</sub> (1)	V <sub>RSM</sub> (1)
ZP1350-25	2500	2700
ZP1350-26	2600	2800
ZP1350-28	2800	3000
ZP1350-30	3000	3200
ZP1350-32	3200	3400
ZP1350-35	3500	3700

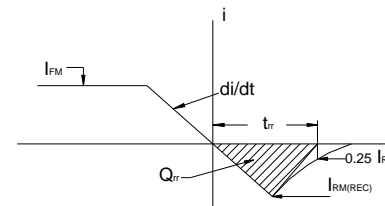
Notes:

All ratings are specified for T<sub>j</sub>=25 °C unless otherwise stated.

- (1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range 0 to +150 °C.
- (2) 10 msec. max. pulse width
- (3) Maximum value for T<sub>j</sub> = 150 °C.
- (4) See parameter definition below :

V<sub>RRM</sub> = Repetitive peak reverse voltage

V<sub>RSM</sub> = Non repetitive peak reverse voltage (2)



REVERSE RECOVERY CHARACTERIST

Repetitive peak reverse leakage	I <sub>RRM</sub>	5 mA 50 mA (3)
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**Conducting - on state**

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average value of on-state current	I <sub>F(AV)</sub>		1350		A	Sinewave, T <sub>c</sub> =90 °C
RMS value of on-state current	I <sub>FRMS</sub>		2119		A	Nominal value
Peak one cycle surge (non repetitive) current	I <sub>FSM</sub>		18900		A	10 msec (50Hz), sinusoidal wave-shape, 180° conduction, T <sub>j</sub> = 150 °C
I square t	I <sup>2</sup> t		1.7 × 10 <sup>6</sup>		A <sup>2</sup> s	10 msec
Peak on-state voltage	V <sub>FM</sub>		1.60		V	I <sub>FM</sub> = 3000A; T <sub>j</sub> =25°C
Threshold voltage	V <sub>FO</sub>		0.88		V	T <sub>j</sub> =150°C, I=0.5 π I <sub>F(AV)</sub> to 1.5 π I <sub>F(AV)</sub>
Slope resistance	r <sub>F</sub>		0.20		mΩ	T <sub>j</sub> =150°C, I=0.5 π I <sub>F(AV)</sub> to 1.5 π I <sub>F(AV)</sub>
Reverse Recovery Current (4)	I <sub>RM(REC)</sub>				A	I <sub>FM</sub> = 500 A; di/dt = -10 A/s; T <sub>jmax</sub>
Reverse Recovery Charge (4)	Q <sub>rr</sub>			4500	μC	I <sub>FM</sub> = 500 A; di/dt = -10 A/s; T <sub>jmax</sub>
Reverse Recovery Time (4)	t <sub>rr</sub>				μs	I <sub>FM</sub> = 500 A; di/dt = -10 A/s; T <sub>jmax</sub>

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	$T_j$	-40	+150		°C	
Storage temperature	$T_{stg}$	-40	+150		°C	
Thermal resistance - junction to case	$R_{\Theta(j-c)}$		0.022		°C/W	Double sided cooled
Thermal resistance - case to heatsink	$R_{\Theta(c-s)}$		0.005		°C/W	Double sided cooled
Mounting force	P	22	27	25	kN	
Weight	W			0.46	kg.	

\* Mounting surfaces smooth, flat and greaseless

**CASE OUTLINE AND DIMENSIONS**

